



US008031320B2

(12) **United States Patent**
Lee et al.

(10) **Patent No.:** **US 8,031,320 B2**
(45) **Date of Patent:** **Oct. 4, 2011**

(54) **LCD PANEL AND ARRAY SUBSTRATE THEREOF**

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(*) Notice: Subject to any disclaimer, the term of this patent is extended or adjusted under 35 U.S.C. 154(b) by 215 days.

(21) Appl. No.: **12/346,077**

(22) Filed: **Dec. 30, 2008**

(65) **Prior Publication Data**

US 2010/0002182 A1 Jan. 7, 2010

(30) **Foreign Application Priority Data**

Jul. 1, 2008 (TW) 97124673 A

(51) **Int. Cl.**
G02F 1/1339 (2006.01)

(52) **U.S. Cl.** **349/154**; 349/153; 349/190; 349/138

(58) **Field of Classification Search** 349/154
See application file for complete search history.

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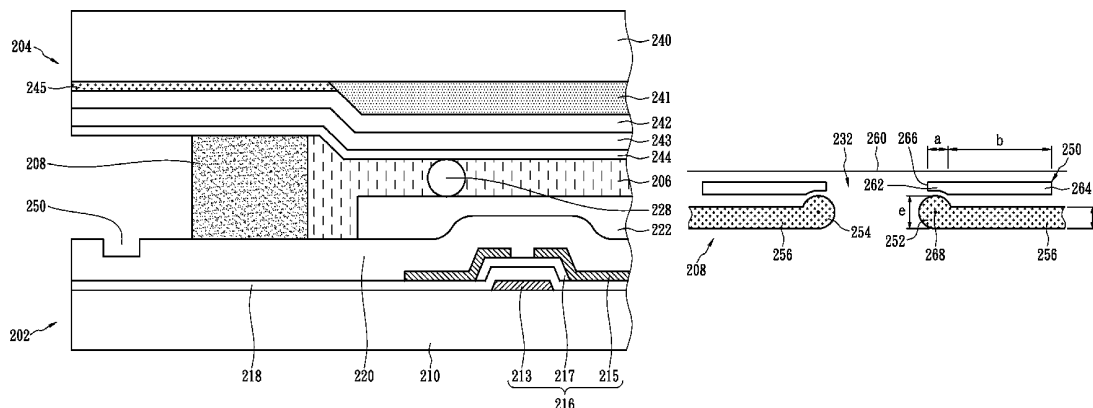
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(57) **ABSTRACT**

An LCD panel includes an array substrate, an opposite substrate and a liquid crystal layer. The opposite substrate is opposite to the array substrate, and the liquid crystal layer is disposed between the array substrate and the opposite substrate. The array substrate includes a substrate, an array, a sealant and a stop structure. The array disposed on the substrate is a thin-film transistor array or a color filter array. The sealant has a first end and a second end, and the first and second ends form an inlet. The stop structure is placed at least between the first end of the sealant frame and a side of the substrate.

7 Claims, 9 Drawing Sheets



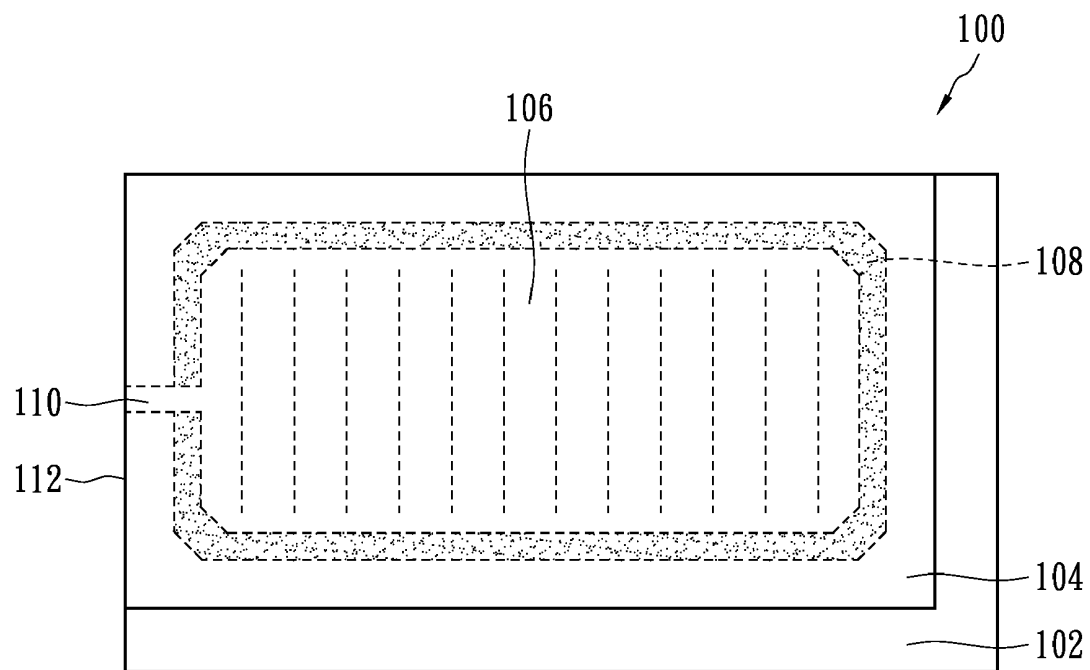


FIG. 1 (Prior Art)

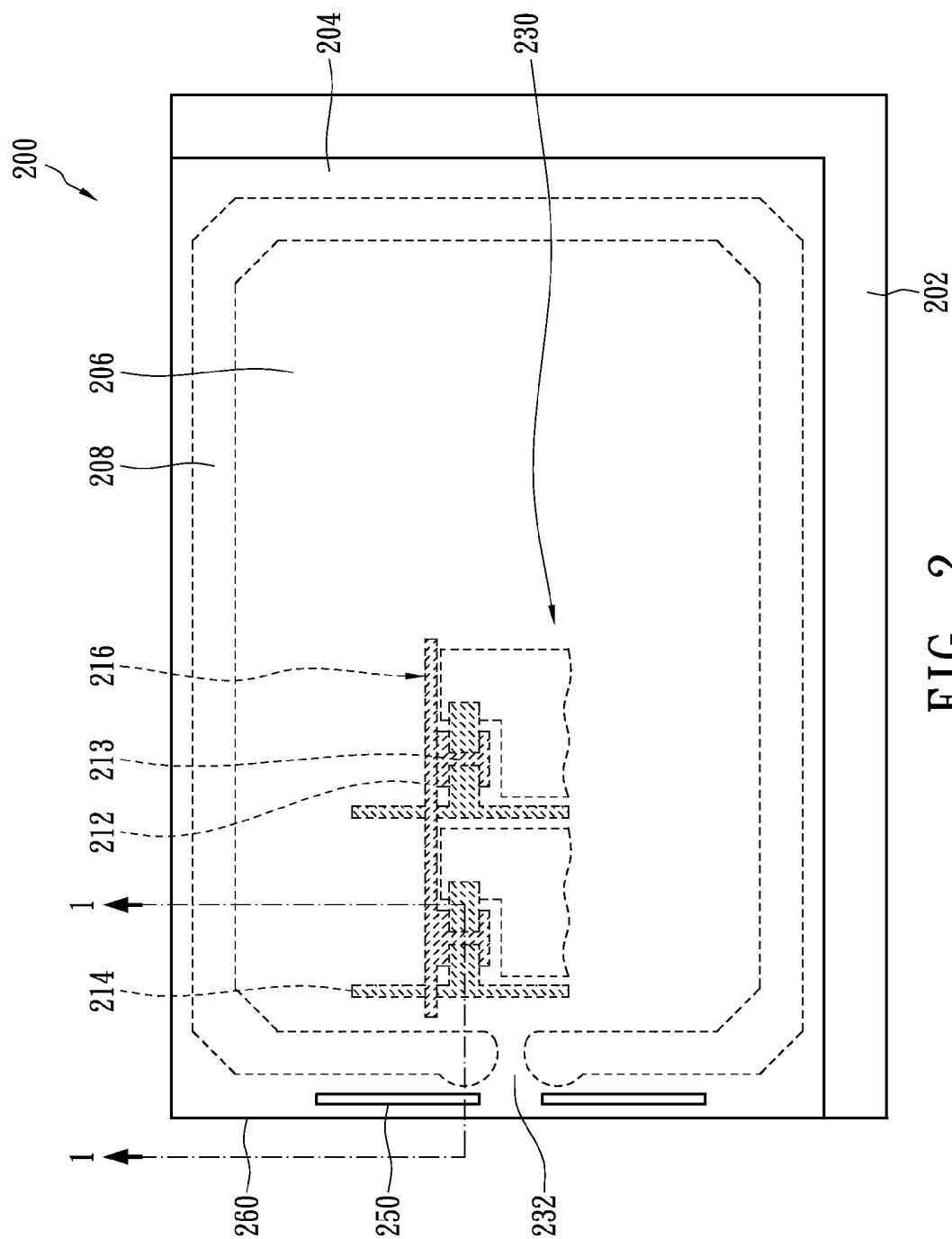


FIG. 2

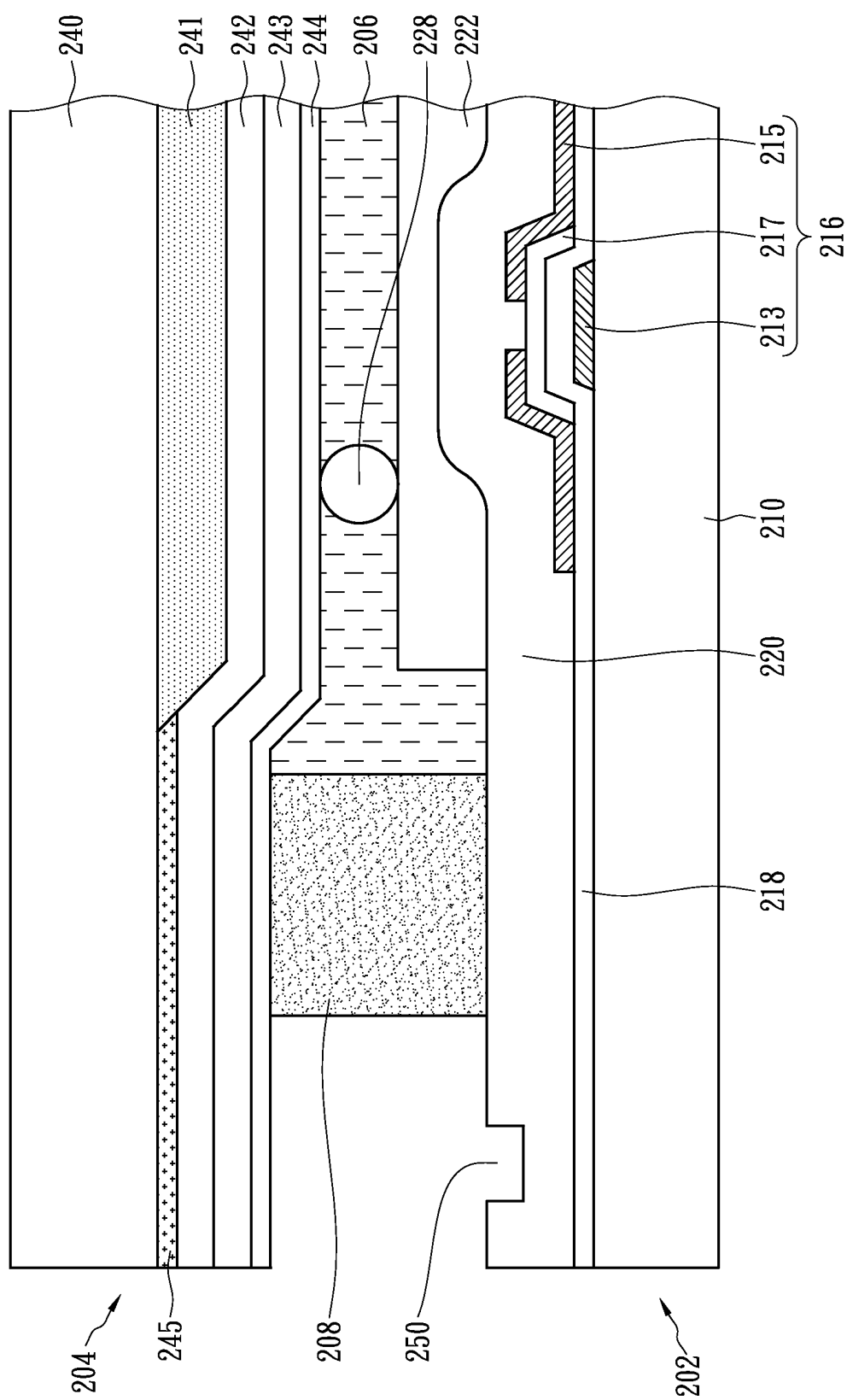


FIG. 3

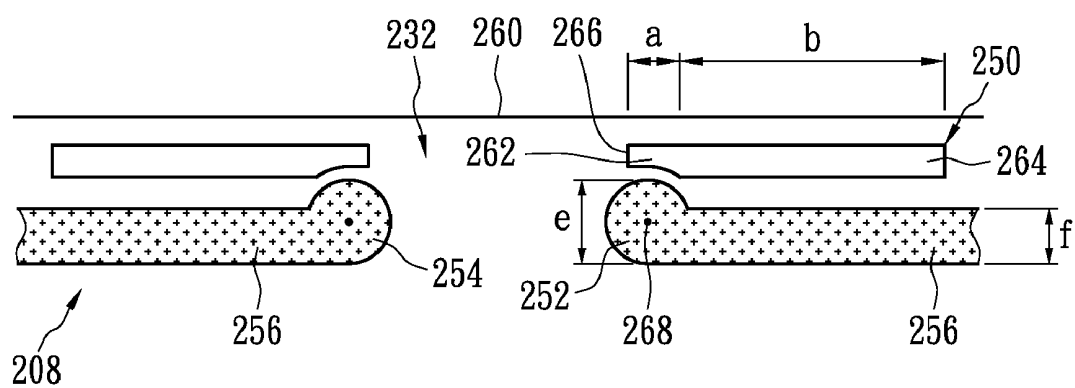


FIG. 4

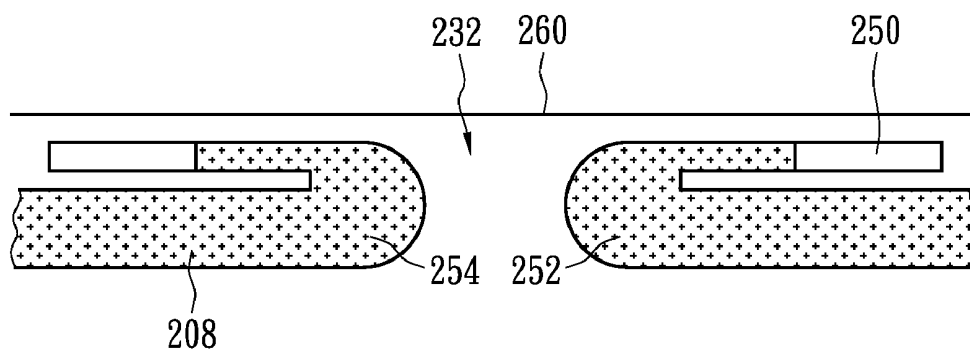


FIG. 5

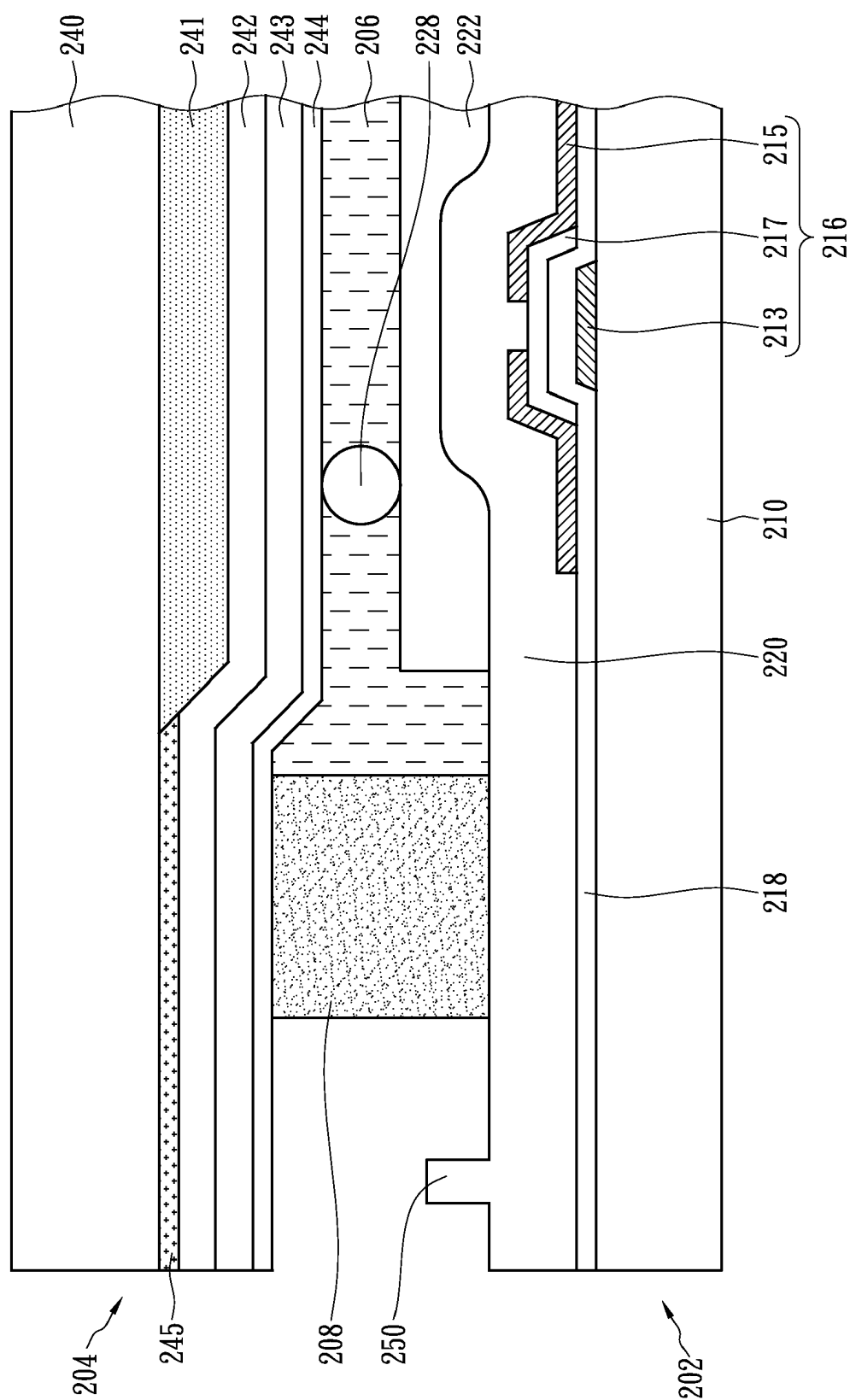


FIG. 6

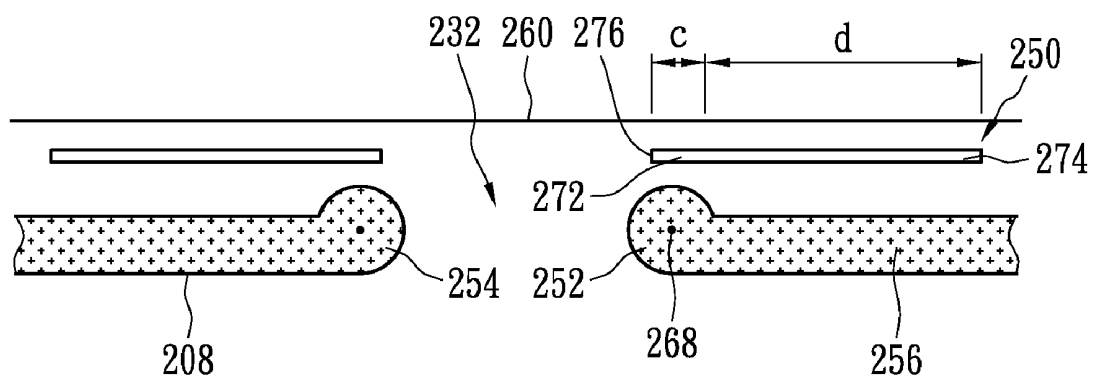


FIG. 7

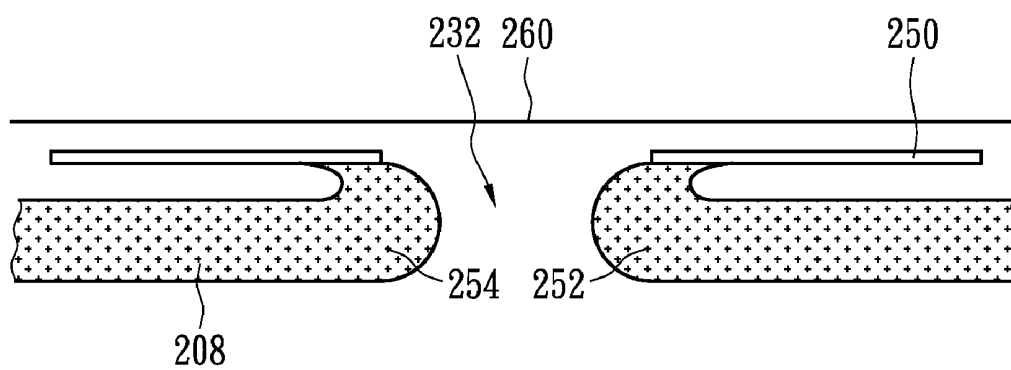


FIG. 8

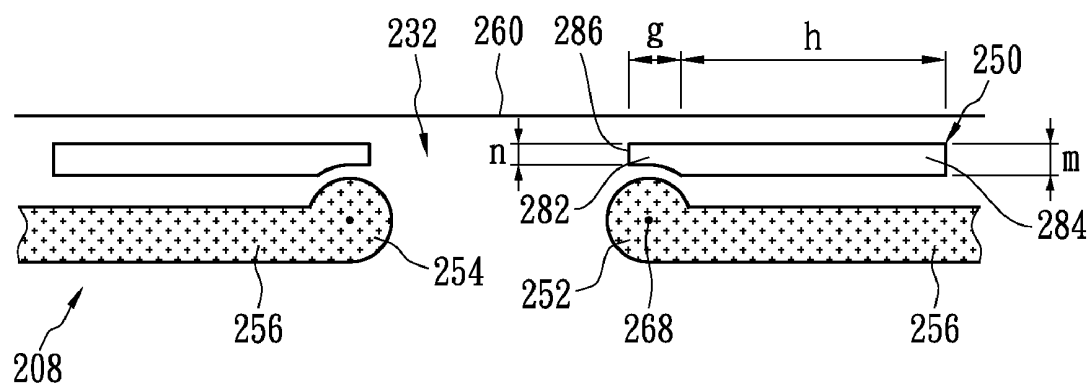


FIG. 9

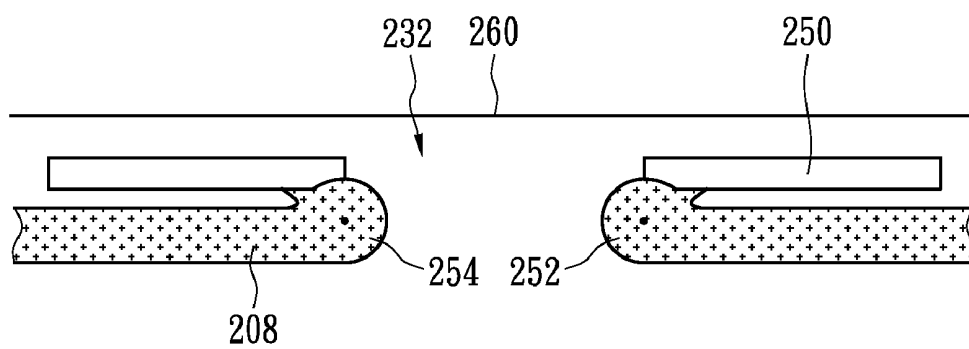


FIG. 10

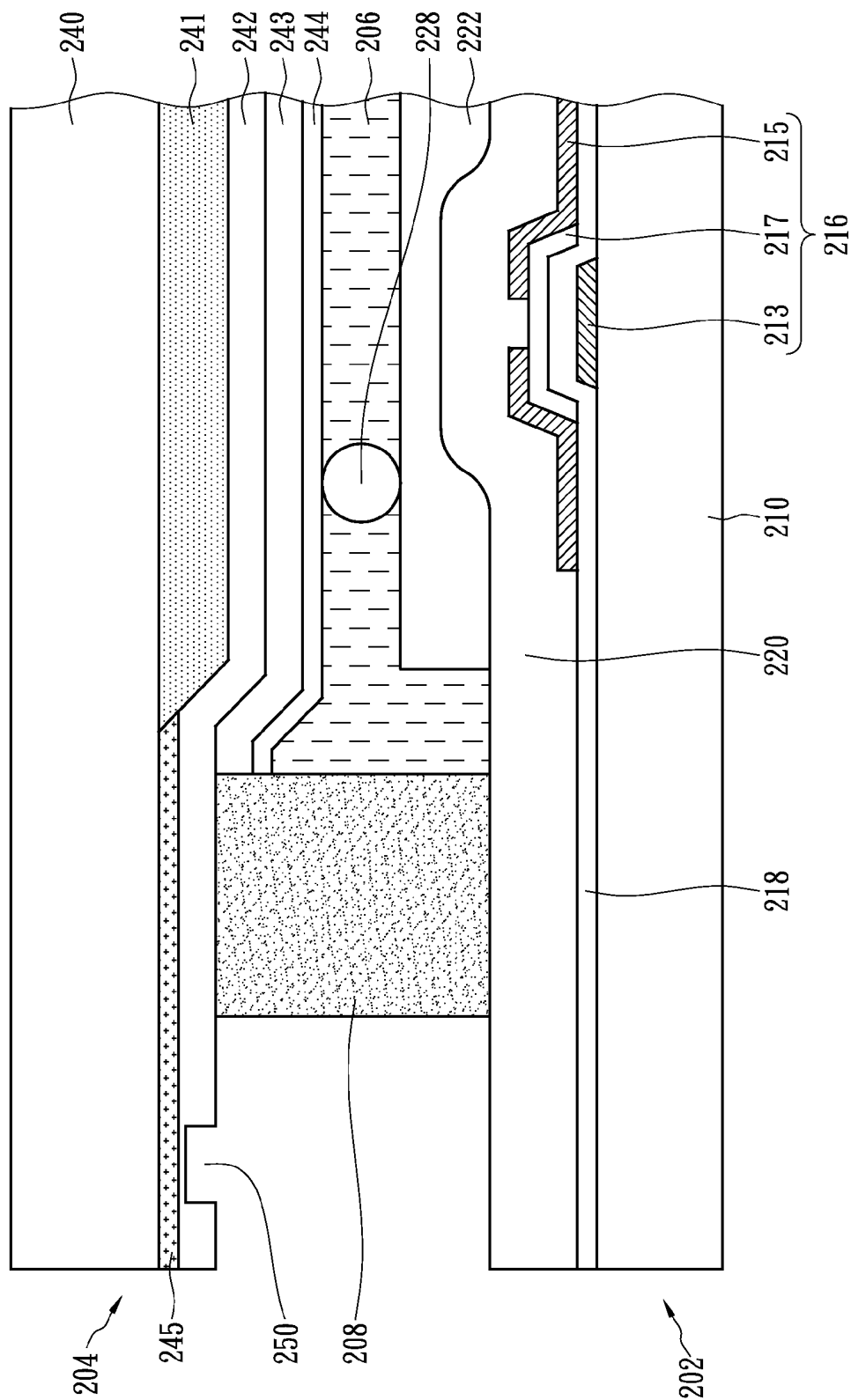


FIG. 11

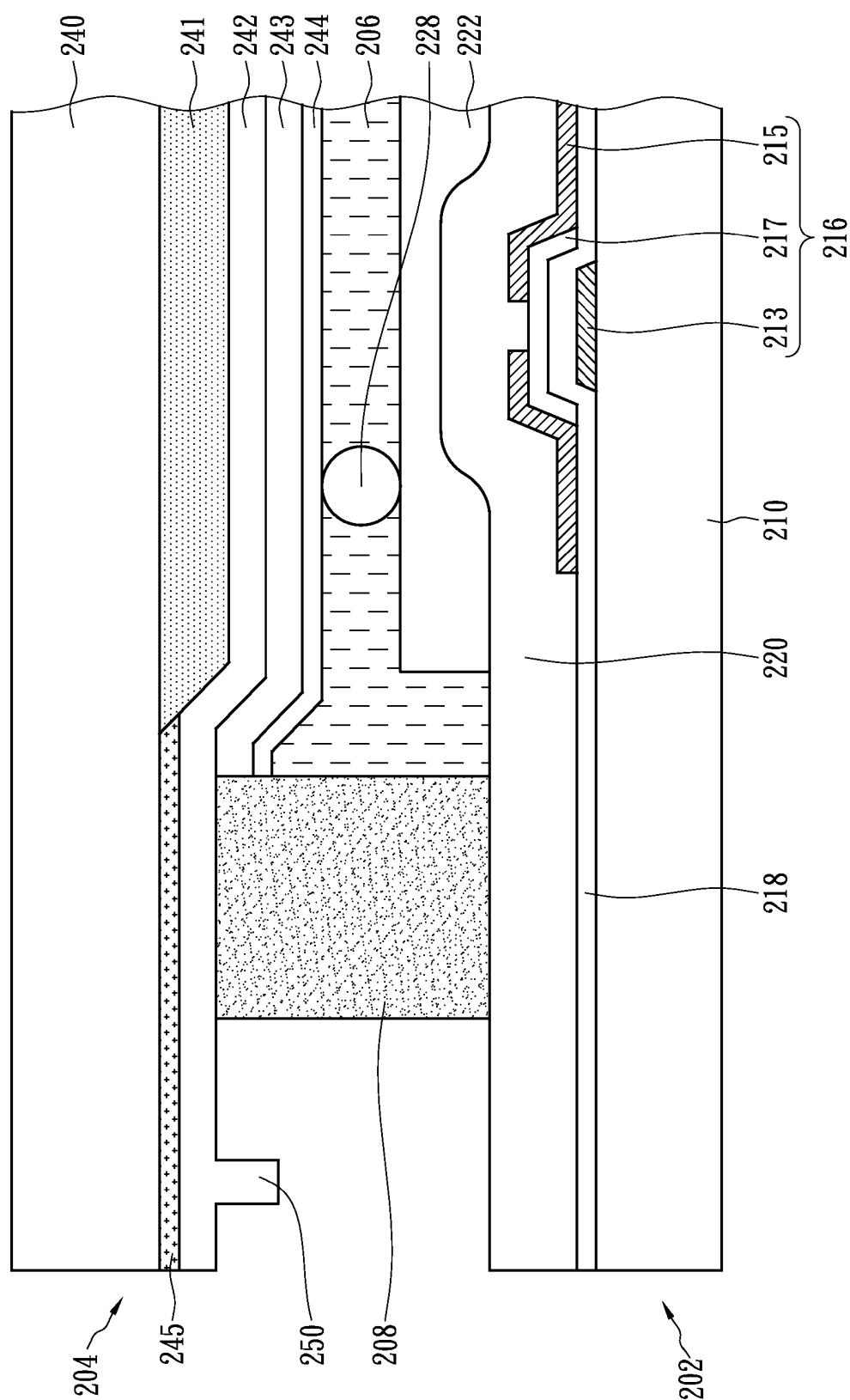


FIG. 12

LCD PANEL AND ARRAY SUBSTRATE THEREOF

BACKGROUND OF THE INVENTION

(A) Field of the Invention

The present invention relates to a liquid crystal display (LCD) panel and the array substrate thereof, and more specifically, to an LCD panel and the array substrate with a sealant-stop structure of a liquid crystal inlet.

(B) Description of Related Art

LCDs have many advantages such as thin panel, light weight, low power consumption and low radiation, and therefore are widely used in current display applications. An LCD display mainly includes an LCD panel and a backlight unit. The backlight unit serves as illumination source to the LCD panel, and the rotations of the liquid crystals are controlled by electrical signals so as to display images.

FIG. 1 shows the top perspective view of an LCD panel 100, wherein the color filter (CF) array substrate 104 is placed above the thin-film transistor (TFT) array substrate 102. For the LCD cell manufacturing, a sealant frame 108 is formed around the perimeter of the CF array substrate 104 or the TFT array substrate 102 to be a boundary after the CF array substrate 104 and the TFT array substrate 102 are assembled. A liquid crystal inlet 110 is formed between the two ends of the sealant frame 108, and liquid crystal 106 is injected into the space confined by the sealant frame 108, the TFT array substrate 102 and the CF array substrate 104.

SUMMARY OF THE INVENTION

The present invention provides an LCD panel and the array substrate thereof with a sealant-stop structure to avoid the overflow of the sealant frame while assembling the substrates, thereby preventing the cutting problem due to the overflow exceeding the scrape line. Moreover, in accordance with the present invention, the change or modification for the processes and the machines is not needed. The present invention can be accomplished by the current manufacturing processes, and therefore is cost-effective.

In accordance with an embodiment of the present invention, an LCD panel includes an array substrate, an opposite substrate and a liquid crystal layer. The opposite substrate is placed opposite to the array substrate, and the liquid crystal layer is disposed between the array substrate and the opposite substrate. The array substrate may be a TFT array substrate or a CF array substrate.

In an embodiment, the array substrate includes a substrate, an array, a sealant frame and a sealant-stop structure. The array may be a thin-film transistor array or a color filter array, and is disposed on the substrate. The sealant frame includes a first end and a second end, and the first and second ends form a liquid crystal inlet. The sealant-stop structure is placed on the substrate and placed at least between the first end of the sealant frame and a side of the substrate.

According to the embodiments of the present invention, the sealant-stop structure may be in the form of a trench or a bulged strip. As a result, the overflow of the sealant frame when assembling the array substrate and the opposite substrate is guided and accommodated in the trench or blocked by the bulged strip, so that the overflow is prevented from extending to the side of the substrate, i.e., a cutting line of the mother panel, and the cutting problems can be resolved.

BRIEF DESCRIPTION OF THE DRAWINGS

FIG. 1 illustrates a top perspective view of a conventional LCD panel;

FIG. 2 illustrates a top view of an LCD panel in accordance with the present invention;

FIG. 3 illustrates the cross-sectional view along line 1-1 of FIG. 2 according to a first embodiment of the present invention;

FIG. 4 illustrates an enlarged view of the sealant-stop structure and a portion of the sealant frame according to the first embodiment of the present invention;

FIG. 5 illustrates the enlarged view of the sealant-stop structure and a portion of the sealant frame when assembling the upper and lower substrates according to the first embodiment of the present invention;

FIG. 6 illustrates the cross-sectional view along line 1-1 of FIG. 2 according to a second embodiment of the present invention;

FIG. 7 illustrates an enlarged view of the sealant-stop structure and a portion of the sealant frame according to the second embodiment of the present invention;

FIG. 8 illustrates the enlarged view of the sealant-stop structure and a portion of the sealant frame in FIG. 7 when assembling the upper and lower substrates of the LCD panel of FIG. 6 according to the second embodiment of the present invention;

FIG. 9 illustrates an enlarged view of the sealant-stop structure modified from the sealant-stop structure in FIG. 7 and a portion of the sealant frame;

FIG. 10 illustrates the enlarged view of the sealant-stop structure and a portion of the sealant frame in FIG. 9 when assembling the upper and lower substrates of the LCD panel of FIG. 6;

FIG. 11 illustrates the cross-sectional view along line 1-1 of FIG. 2 according to a third embodiment of the present invention; and

FIG. 12 illustrates the cross-sectional view along line 1-1 of FIG. 2 according to a fourth embodiment of the present invention.

DETAILED DESCRIPTION OF THE INVENTION

Referring to FIG. 1, when outputting the sealant to form the sealant frame 108 and liquid crystal inlet 110, because the beginning and the end of the sealant frame are difficult to control well, the beginning and the end of the sealant frame 108 may overflow after or while the CF array substrate 104 and the TFT array substrate 102 are assembled. If the overflow exceeds a cutting line of the mother panel, e.g., a side 112 adjacent to the liquid crystal inlet 110 of the LCD panel 100, the panel is difficult cut and breach or damage of the panel may occur.

The making and using of the presently preferred embodiments are discussed in detail below. It should be appreciated, however, that the present invention provides many applicable inventive concepts that can be embodied in a wide variety of specific contexts. The specific embodiments discussed are merely illustrative of specific ways to make and use the invention, and do not limit the scope of the invention.

FIG. 2 illustrates an LCD panel 200 in accordance with an embodiment of the present invention, and FIG. 3 illustrates the cross-sectional view along line 1-1 of FIG. 2 in accordance with a first embodiment of the present invention. The LCD panel 200 includes a TFT array substrate 202, a CF array substrate 204, at least one stop structure, a sealant which may be a sealant frame 208 for example, and a liquid crystal layer 206. The liquid crystal layer 206 is injected into the space confined by the TFT array substrate 202, the CF array substrate 204 and the sealant frame 208 through an inlet which

may be a liquid crystal inlet **232** for example. The at least one stop structure is located adjacent to the liquid crystal inlet **232** and side **260**.

The TFT array substrate **202** includes a substrate **210**, scan lines **212**, data lines **214**, thin-film transistors **216**, a gate dielectric layer **218**, a passivation layer **220** and a planarization layer **222**. As shown in FIG. 3, however, the planarization layer **222** may be formed completely on the passivation layer **220** so that the sealant frame **208** is disposed on the planarization layer **222**, but not limited thereto. The material of the passivation layer **220** may be organic materials, inorganic materials such as silicon oxide or silicon nitride. A polyimide (PI) layer (not shown) is formed on the planarization layer **222**. The scan lines **212** and the data lines **214** are substantially perpendicular, and each intersection is provided with a thin-film transistor **216**. The thin-film transistors **216** are arranged as an array to form a thin-film transistor array **230**. A thin-film transistor **216** includes a gate electrode **213**, source/drain electrodes **215** and a channel layer **217**. The gate dielectric layer **218** is formed on the substrate **210** and covers the gate electrode **213** of the thin-film transistor **216**. The passivation layer **220** is formed on the gate dielectric layer **218** and covers the source/drain electrodes **215** and the channel layer **217** of the thin-film transistor **216**.

It should be noted that the LCD panel **200** of FIG. 2 is not illustrated according to actual scale; in order to clearly show structural features, the scan lines **212**, the data lines **214** and the thin-film transistors **216** are much larger than other components.

The CF array substrate **204** essentially includes a substrate **240**, a shielding layer **245**, a color filter layer **241**, a passivation layer **242**, a transparent electrode layer **243** and an alignment layer **244**. The shielding layers **245** are formed as black matrix, and the color filter layers **241** are formed as a color filter array. In an embodiment, the material of the passivation layer **242** may include organic materials, while the material of the shielding layer **245** may include epoxy, metal or other light-shielding metal.

The TFT array substrate **202** and the CF array substrate **204** are spaced by spacers **228** to form room for receiving the liquid crystal layer **206**. The liquid crystal inlet **232** is formed between two ends of the sealant frame **208**. According to the present invention, stop structure which may be a sealant-stop structure **250** herein is formed between the sealant frame **208** in the vicinity of the liquid crystal inlet **232** and a side **260** of the LCD panel **200**, so as to prevent the sealant frame **208** from overflowing when assembling the substrates **202** and **204**. The side **260** is equivalent to a cutting line before cutting the panel **200**.

In FIG. 3, the sealant-stop structure **250** is a trench and formed in the passivation layer **220**. The passivation layer **220** may be comprised of organic or inorganic oxide such as silicon oxide or silicon nitride. A top view of the sealant-stop structure **250** according to an embodiment is shown in FIG. 4. The sealant frame **208** includes a first end **252**, a second end **254** and a body portion **256**. It should be noted that the sealant frame **208** is not limited to a continuous pattern; a discontinuous pattern with multiple ends can be used also. In this embodiment, any two ends of the sealant frame **208** are exemplified to define the liquid crystal inlet **232**. The body portion **256** is connected to the first end **252**, surrounds the TFT array **230** and is connected to the second end **254**. Because the places of the beginning and the end of the sealant frame **208** are usually provided with a large amount of sealant, the width "e" of the first end **252** or the second end **254** is larger than the width "f" of the body portion **256**. In an embodiment, the sealant-stop structure **250** may include a first portion **262** and

a second portion **264**. An end **266** of the first portion **262** exceeds the center **268** of the beginning or the end of the sealant frame **208**, i.e., the center **268** of the first end **252** or the second end **254**. The first portion **262** is placed between the first end **252** and the side **260**. The second portion **264** is connected to the first portion **262**, and placed between the body portion **256** and the side **260**, and extends away from the liquid crystal inlet **232**. The width "b" of the second portion **264** is larger than the width "a" of the first portion **262**.

In FIG. 5, when the TFT array substrate **202** and the CF array substrate **204** are combined or assembled, the overflow at the first end **252** and the second end **254** caused by assembling will be guided to the sealant-stop structure **250** which is a trench, and from the first portion **262** to the second portion **264**. As a result, the overflow is prevented from exceeding the side **260** (i.e., the cutting line).

FIG. 6 illustrates the cross-sectional view along line 1-1 of FIG. 2 according to a second embodiment. In addition to a trench, the sealant-stop structure **250** may be a bulged strip formed on the passivation layer **220**. In other words, the passivation layer **220** forms the bulged strip. FIG. 7 illustrates an enlarged view of the sealant-stop structure **250** and a portion of the sealant frame in accordance with the second embodiment. Compared to the trench shown in FIG. 4, the sealant-stop structure **250** of FIG. 7 is a bulged strip that may include a first portion **272** and a second portion **274**. An end **276** of the first portion **272** exceeds the center **268** of the beginning or the end of the sealant frame **208**, i.e., the center **268** of the first end **252** or the second end **254**. The first portion **272** is placed between the first end **252** and the side **260**. The second portion **274** is connected to the first portion **272**, and placed between the body portion **256** and the side **260**, and extends away from the liquid crystal inlet **232**. The length "d" of the second portion **274** is larger than the length "c" of the first portion **272**.

In FIG. 8, when the TFT array substrate **202** and the CF array substrate **204** shown in FIG. 6 are combined or assembled, the overflow at the first end **252** and the second end **254** caused by assembling will be blocked by the sealant-stop structure **250** (the bulged strip), and guided between the sealant frame **208** and the sealant-stop structure **250**. As a result, the overflow is prevented from exceeding the side **260** (i.e., the cutting line).

FIG. 9 illustrates an enlarged view of the sealant-stop structure **250** in the form of the bulged strip modified from the sealant-stop structure **250** in FIG. 7 and a portion of the sealant frame **208**. The sealant-stop structure **250** includes a first portion **282** and a second portion **284**. An end **286** of the first portion **282** exceeds the center **268** of the beginning or the end of the sealant frame **208**, i.e., the center **268** of the first end **252** or the second end **254**. The first portion **282** is placed between the first end **252** and the side **260**. The second portion **284** connected to the first portion **282** is placed between the body portion **256** and the side **260**, and extends away from the liquid crystal inlet **232**. The length "h" of the second portion **284** is larger than the length "g" of the first portion **282**, and the width "m" of the second portion **284** is larger than the width "n" of the first portion **282**.

In FIG. 10, when the TFT array substrate **202** and the CF array substrate **204** shown in FIG. 6 are combined or assembled, the overflow at the first end **252** and the second end **254** caused by assembling will be blocked by the sealant-stop structure **250** (the bulged strip), and guided between the sealant frame **208** and the sealant-stop structure **250**. As a result, the overflow is prevented from exceeding the side **260** (i.e., the cutting line).

However, if the passivation layer **220** does not extend out of the sealant frame **208**, the sealant-stop structure **250** that may be a trench or a bulged strip also can be formed in the gate dielectric layer **218**. The gate dielectric layer **218** may be comprised of silicon oxide or silicon nitride.

FIG. **11** illustrates the cross-sectional view along line **1-1** of FIG. **2** according to a third embodiment. In this embodiment, the sealant-stop structure **250** is in the form of a trench that is formed in the passivation layer **242** of the CF array substrate **204**. The passivation layer **242** may be comprised of organic material. When assembling the TFT array substrate **202** and the CF array substrate **204**, the CF array substrate **204** is placed underneath the TFT array substrate **202** (i.e., an upside-down view of FIG. **11**), and the overflow-prevention mechanism is similar to that of FIG. **5**. The overflow caused by assembling the substrate **202** and the substrate **204** is guided to the trench of the sealant-stop structure **250**, thereby preventing the overflow from exceeding the side **260** (i.e., the cutting line). However, the transparent electrode layer **243** may be formed to substantially extend to the side **260** of the substrate **240**, and covers the sealant-stop structure **250** so that the sealant frame **208** is disposed on the transparent electrode layer **243**.

FIG. **12** illustrates the cross-sectional view along line **1-1** of FIG. **2** according to a fourth embodiment of the present invention. In this embodiment, the sealant-stop structure **250** is in the form of a bulged strip and is formed in the passivation layer **242** of the CF array substrate **204**. For instance, the thickness of the bulged strip is in the range of 4 to 6 micrometers. However, the transparent electrode layer **243** may be formed to substantially extend to the side **260** of the substrate **240**, and covers the sealant-stop structure **250** so that the sealant frame **208** is disposed on the transparent electrode layer **243**.

However, if the passivation layer **242** does not extend out of the sealant frame **208**, the sealant-stop structure **250** that may be a trench or a bulged strip also can be formed in the shielding layer **245** (black matrix), i.e., the shielding layer **245** forms the sealant-stop structure **250**. The shielding layer **245** may include epoxy, metal or inorganic oxide. Moreover, if the color filter layer **241** extends out of the sealant frame **208**, the sealant-stop structure **250** that may be a trench or a bulged strip also can be formed in the color filter layer **241**, i.e., the color filter layer **241** forms the sealant-stop structure **250**. The material of the stop structure **250** is comprised of inorganic oxide, organic material, color resist or epoxy. As a result, the overflow is prevented from exceeding the side **260** (i.e., the cutting line), and the cutting problems can be avoided.

The present invention can be accomplished by current processes in production without changing current processes and machines. The sealant-stop structure in the vicinity of the liquid crystal inlet is formed on either the TFT array substrate or the CF array substrate by performing developing and etch-

ing processes, and therefore the overflow is guided to other places or accommodated in the trench. As a result, the overflow of the sealant frame is prevented from exceeding the cutting line, so as to avoid cutting problems.

The above-described embodiments of the present invention are intended to be illustrative only. Numerous alternative embodiments may be devised by those skilled in the art without departing from the scope of the following claims.

What is claimed is:

1. A liquid crystal display panel, comprising:
an array substrate, comprising:
a substrate;
an array including a passivation layer, disposed on the substrate;
a sealant having a first end and a second end, disposed on the substrate and substantially surrounding the array, wherein the first end and the second end form an inlet, wherein the passivation layer has a stop structure located between the first end of the sealant and a side of the substrate, wherein the sealant further has a body portion connected to the first end, and the first end is wider than the body portion;
an opposite substrate disposed opposite to the array substrate, wherein the sealant is substantially located between the passivation layer and the opposite substrate; and
a liquid crystal layer disposed between the array substrate and the opposite substrate.
2. The liquid crystal display panel of claim 1, wherein the array is a thin film transistor array or a color filter array.
3. The liquid crystal display panel of claim 1, wherein the stop structure has:
a first portion placed between the first end and the side of the substrate; and
a second portion connected to the first portion and placed between the body portion and the side of the substrate, wherein the second portion is wider than the first portion.
4. The liquid crystal display panel of claim 3, wherein the first portion comprises a first trench, the second portion comprises a second trench, and the second trench extends away from the inlet.
5. The liquid crystal display panel of claim 3, wherein the first portion comprises a first bulged strip, the second portion comprises a second bulged strip, and the second bulged strip extends away from the inlet.
6. The liquid crystal display panel of claim 3, wherein the material of the stop structure comprises inorganic oxide, organic material, color resist or epoxy.
7. The liquid crystal display panel of claim 1, wherein the material of the stop structure comprises inorganic oxide, organic material, color resist or epoxy.

* * * * *

专利名称(译)	LCD面板及其阵列基板		
公开(公告)号	US8031320	公开(公告)日	2011-10-04
申请号	US12/346077	申请日	2008-12-30
[标]申请(专利权)人(译)	友达光电股份有限公司		
申请(专利权)人(译)	友达光电股份有限公司		
当前申请(专利权)人(译)	友达光电股份有限公司		
[标]发明人	LEE CHUNG TA WU YU TUNG		
发明人	LEE, CHUNG TA WU, YU TUNG		
IPC分类号	G02F1/1339		
CPC分类号	G02F1/1339 G02F1/1341		
审查员(译)	NGUYEN , THANH环		
优先权	097124673 2008-07-01 TW		
其他公开文献	US20100002182A1		
外部链接	Espacenet USPTO		

摘要(译)

LCD面板包括阵列基板，相对基板和液晶层。对向基板与阵列基板相对，液晶层设置在阵列基板和相对基板之间。阵列基板包括基板，阵列，密封剂和光阑结构。设置在基板上的阵列是薄膜晶体管阵列或滤色器阵列。密封剂具有第一端和第二端，第一和第二端形成入口。止挡结构至少放置在密封剂框架的第一端和基板的侧面之间。

